Low frequency transistor (–20V, –5A) 2SB1386 / 2SB1412

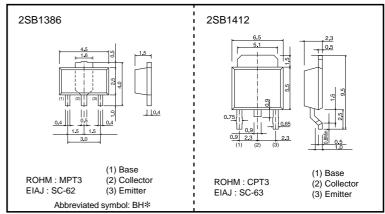
Features

- 1) Low VCE(sat). VCE(sat) = -0.35V (Typ.)(Ic/IB = -4A/-0.1A)
- 2) Excellent DC current gain characteristics.
- 3) Complements the 2SD2098 / 2SD2118.

Structure

Epitaxial planar type PNP silicon transistor

●Dimensions (Unit:mm)



^{*} Denotes hre

● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-30	V	
Collector-emitter voltage		Vceo	-20	V	
Emitter-base voltage		VEBO	-6	V	
		lc	-5	A(DC)	
Collector current	collector current		-10	A(Pulse) *1	
	0004000		0.5	W	
Collector power	2SB1386		W *2		
dissipation	2SB1412	Pc	1	W	
			10	W(Tc=25°C)	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to 150	°C	

^{*1} Single pulse, Pw=10ms

^{*2} When mounted on a 40×40×0.7 mm ceramic board.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-30	_	_	V	Ic= -50μA
Collector-emitter breakdown voltage	BVceo	-20	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	ВУево	-6	_	_	V	I==-50μA
Collector cutoff current	Ісво	_	_	-0.5	μΑ	Vcb= -20V
Emitter cutoff current	ІЕВО	_	_	-0.5	μΑ	V _{EB} = -5V
Collector-emitter saturation voltage	VCE(sat)	_	0.35	-1.0	V	Ic/I _B = -4A/ -0.1A *
DC current transfer ratio	hfe	82	_	390	_	Vce= -2V, Ic= -0.5A *
Transition frequency	f⊤	_	120	_	MHz	Vc==-6V, I==50mA, f=100MHz
Output capacitance	Cob	_	60	_	pF	Vcb= -20V, Ie=0A, f=1MHz

st Measured using pulse current.

●Packaging specifications and hfe

		Package	Тар	oing
		Code	T100	TL
Туре	hfe	Basic ordering unit (pieces)	1000	2500
2SB1386	PQR		0	-
2SB1412	PQR		_	0

hre values are classified as follows:

Item	Р	Q	R
hfe	82 to 180	120 to 270	180 to 390

ROHM

•Electrical characteristic curves

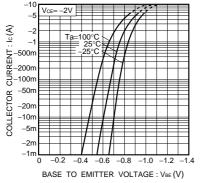


Fig.1 Grounded emitter propagation characteristics

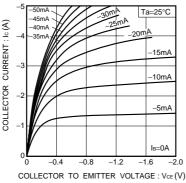


Fig.2 Grounded emitter output characteristics

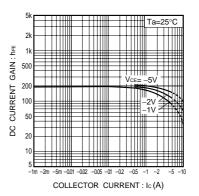


Fig.3 DC current gain vs. collector current (I)

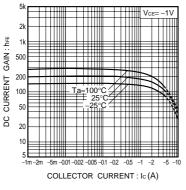


Fig.4 DC current gain vs. collector current (II)

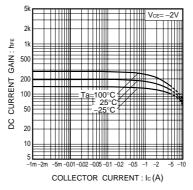


Fig.5 DC current gain vs. collector current (III)

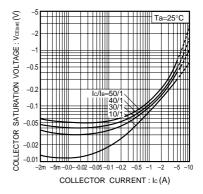


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

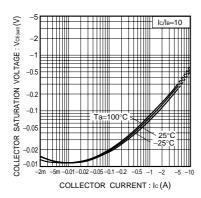


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

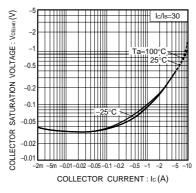


Fig.8 Collector-emitter saturation voltage vs. collector current (III)

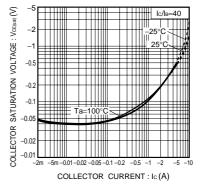
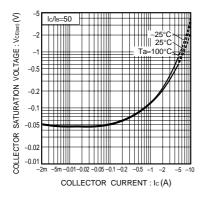
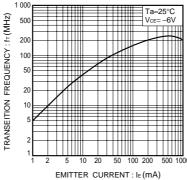


Fig.9 Collector-emitter saturation voltage vs. collector current (IV)





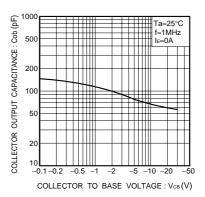


Fig.10 Collector-emitter saturation voltage vs. collector current (V)

Fig.11 Gain bandwidth product vs. emitter current

Fig.12 Collector output capacitance vs. collector-base voltage

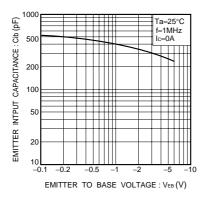
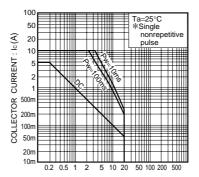


Fig.13 Emitter input capacitance vs. emitter-base voltage



COLLECTOR TO EMITTER VOLTAGE: -VCE (V)

Fig.14 Safe operation area (2SB1412)

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
 means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
 product described in this document are for reference only. Upon actual use, therefore, please request
 that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
 use and operation. Please pay careful attention to the peripheral conditions when designing circuits
 and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

It is our top priority to supply products with the utmost quality and reliability. However, there is always a chance of failure due to unexpected factors. Therefore, please take into account the derating characteristics and allow for sufficient safety features, such as extra margin, anti-flammability, and fail-safe measures when designing in order to prevent possible accidents that may result in bodily harm or fire caused by component failure. ROHM cannot be held responsible for any damages arising from the use of the products under conditions out of the range of the specifications or due to non-compliance with the NOTES specified in this catalog.

Thank you for your accessing to ROHM product informations.

More detail product informations and catalogs are available, please contact your nearest sales office.

ROHM Customer Support System

THE AMERICAS / EUPOPE / ASIA / JAPAN

www.rohm.com

Contact us : webmaster@rohm.co.jp

Copyright © 2007 ROHM CO.,LTD.

ROHM CO., LTD. 21, Saiin Mizosaki-cho, Ukyo-ku, Kyoto 615-8585, Japan

oan TEL:+81-75-311-2121 FAX:+81-75-315-0172

